TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA7280P,TA7281P

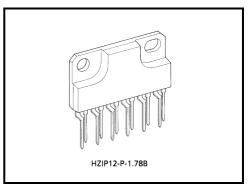
5.8W Dual Audio Power Amplifier. 22W BTL Audio Power Amplifier.

The TA7280P, TA7281P are dual audio power amplifier for consumer applications.

It is designed for high power, low distortion and low noise. It also contains various kind of protectors.

It is suitable for car-audio power amplifier with high performance.

The kinds of pin configuration are available: Normal (TA7280P) and reverse (TA7281P) for easier layout design of PC-board when used in BTL-stereo application.



Weight: 4.04g (typ.)

FeaturesHigh power

ingli power : POUT (1) = 22W (typ.) (VCC = 14.4V, f = 1kHz, THD = 10%, R_L = 4 Ω , BTL) POUT (2) = 19W (typ.) (VCC = 13.2V, f = 1kHz, THD = 10%, R_L = 4 Ω , BTL) POUT (3) = 15W (typ.) (VCC = 13.2V, f = 1kHz, THD = 1%, R_L = 4 Ω , BTL) POUT (4) = 5.8W (typ.) / ch

(V_{CC} = 13.2V, f = 1kHz, THD = 10%, R_L = 4 Ω , DUAL)

• Low distortion

: THD (1) = 0.03% (typ.) (V_{CC} = 13.2V, f = 1kHz, P_{OUT} = 4W, R_L = 4 Ω , G_V = 40dB, BTL) THD (2) = 0.06% (typ.) (V_{CC} = 13.2V, f = 1kHz, P_{OUT} = 1W, R_L = 4 Ω , G_V = 52dB, DUAL)

• Low noise

: V_{NO} (1) = 0.14m V_{rms} (typ.) (V_{CC} = 13.2V, R_L = 4 Ω , G_V = 40dB, R_g = 0, DIN noise: DIN45405, BTL) V_{NO} (2) = 0.7m V_{rms} (typ.) (V_{CC} = 13.2V, R_L = 4 Ω , G_V = 52dB, R_g = 10k Ω , BW = 20Hz~20kHz, DUAL)

• Protector circuit

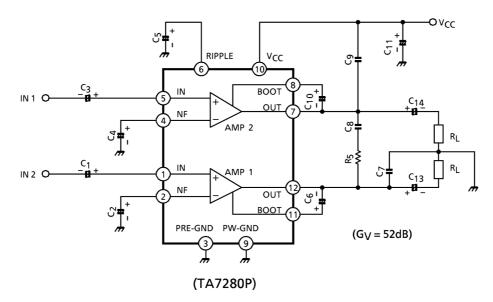
: Thermal shout down, Over voltage protection, $\mbox{Out-V}_{\mbox{CC}}$ short, $\mbox{Out-GND}$ short and $\mbox{Out-Out}$ short protection.

• Operating supply voltage range

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: VCC (opr) = 9 \sim 18V
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TOSHIBA Block Diagram

DUAL



Application Information(this explanatory terminal number is for TA7280P)

1. Voltage gain adjustment

(1) Dual amplifier

The voltage gain GV is determined by R_1 , R_2 and R_f in (Fig. 1).

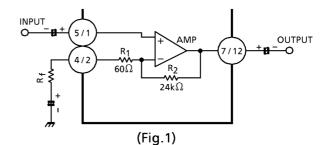
$$G_V=20\lambda og \frac{R_f+R_1+R_2}{R_f+R_1} \left(dB \right)$$

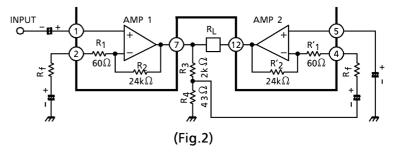
In case of $R_{\rm f}$ = 0

The voltage gain is set as follows: GV = 52dB (typ.) (2) BTL amplifier

The recommended BTL connection amplifier shown in (Fig. 2) . AMP. 1 is noninverting amplifier and AMP. 2 is invert one. The output voltage is divided by resistors R₃ and R₄. The divided voltage is applied to inverting input of amp. 2. R₃ and R₄ are determined in the following equation.

$$\frac{R_3 + R_4}{R_3} = 20 \log \frac{R_f + R_1 + R_2}{R_f + R_1} (dB)$$





GV in Dual mode

The voltage gain in this circuit is 6dB higher than that in Dual mode.

 $G_V = 20 \lambda og \frac{R_f + R_1 + R_2}{R_1 + R_2} (dB)$ $R_f + R_1$ In case of $R_f = 0$ GV = 52 + 6 = 58 (dB)In case of $R_f = 430\Omega$ GV = 34 + 6 = 40 (dB)Each voltage gain can be set as shown above. 2. Muting Audio muting can be accomplished by connecting pin(6) (ripple filter) to GND as shown in (Fig. 3). Then, the bias circuits are cut off. However, caution must be exercised to the following items. (1) The recovery time from the muting operation is determined by the capacities of the ripple filter capacitor between pin(6) and GND, and of the capacitor for NF. (2) As this muting system is operated by the short-circuit of ripple filter: C5, the ripple rejection ratio becomes worse Muting SW in the muting condition. At mute on, some pop noise of breaking the bias are produced. (Fig.3) The output waveform at muting on / off during BTL, are shown in (Fig.4). (Provided VCC = 13.2V, RL = 4Ω , nonsignal.) 50dB or more can be obtained for OUTPUT muting amount. WAVEFORM (1V/div) $\frac{1}{2}$ VCC Pin[®] WAVEFORM (5V/div) 🗕 0.5s / div Mute ON Mute OFF v_{CC} = 13.2V, R_L = 4 $\Omega,$ INPUT short, btl (Fig.4)

3. Measures against oscillation.

C7, C8, C9, C12: The capacitor of polyester film having small variation of the temperature characteristics is recommended as the capacitor for oscillation prevention.

 C_{12} : Reduces the gain in the high range frequency (150kHz or over) and increases the oscillation allowance. R5: Increases the oscillation allowance at output cripping of the low range frequency (100Hz or less).

Since the oscillation allowance varies according to the following item, carry out the temperature test to confirm the oscillation allowance.

(1) Gain to be used (GV setting).

- (2) Capacity of capacitor
- (3) Kinds of capacitor
- (4) Layout of printed board

It is recommended to use the capacitor having the capacity exceeding the oscillation stopping value. At using with the voltage gain GV lowered or with the high range frequency and the oscillation becomes liable to be produced.

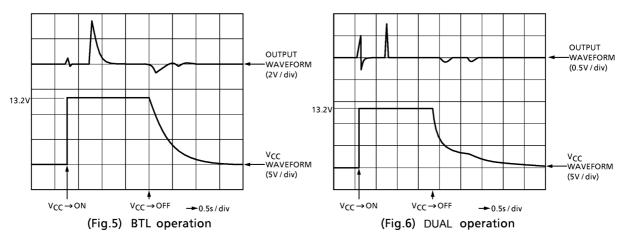
Therefore, application with GV = 40dB or over is advisable.

Especially for using with the gain lowered in dual operation, insert 1000 pF between NF (pin(2) and pin(4)) and GND.

This capacitor reduces the gain of the high range frequency and is effective for oscillation prevention.

4. Output waveform at power supply on / off (reference)

BTL and dual amplifier DC output waveforms in the condition of V_{CC} = 13.2V, R_L = 4 Ω at non-signal (input short) are shown in (Fig. 5) and (Fig. 6).



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The popping time at power supply on / off varies according to the rise and fall times.

The condition in which the power supply is rapidly and repeatedly mode on / off, that is, the condition in which the charge is made on the external capacitor of IC is different from the conditions shown in (Fig. 5) and (Fig. 6) .

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Peak supply voltage (0.2 s)	V _{CC} (surge)	45	V
DC supply voltage	V _{CC (DC)}	25	V
Operating supply voltage	V _{CC (opr)}	18	V
Output current (peak)	I _{O (peak)}	4.5	А
Power dissipation	PD	25	W
Operating temperature	T _{opr}	-30~85	°C
Storage temperature	T _{stg}	-55~150	°C

Electrical Characteristics (unless otherwise specified, V_{CC} = 13.2V, R_L = 4 Ω , R_g = 600 Ω , f = 1kHz, Ta = 25°C)

	Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Quiescent current		ICCQ	2	V _{IN} = 0	—	80	145	mA
U		POUT (1)	1	THD = 10%, V _{CC} = 14.4V	—	22	_	
	Output power	P _{OUT (2)}	1	THD = 10%	16	19	_	W
		P _{OUT (3)}	1	THD = 1%	15	_		
pom uc	Total harmonic distortion	THD (1)	1	P _{OUT} = 4W, G _V = 40dB	-	0.03	0.25	%
BTL connection mode	Output offset voltage	V _{OFF}	1	V _{IN} = 0	_	0	0.35	V
	Voltage gain	G _{V (1)}	1	V _{OUT} = 0.775V _{rms} (0dBm)	—	40		dB
	Output noise voltage	V _{NO (1)}	1	R _g = 0 DIN45405 noise filter	_	0.14	-	mV _{rms}
	Ripple rejection ratio	R. R. (1)	1	f _{ripple} = 100Hz V _{ripple} = 0.775V _{rms} (0dBm)	_	-52	-40	dB
	Output power	POUT (4)	2	THD = 10%	5	5.8	_	W
Dual mode	Total harmonic distortion	THD (2)	2	P _{OUT} = 1W	_	0.06	0.30	%
	Voltage gain	G _{V (2)}	2	V _{OUT} = 0.775V _{rms} (0dBm)	50	52	54	dB
	Voltage gain ratio	ΔG _V	2	V _{OUT} = 0.775V _{rms} (0dBm)	-1	0	1	dB
	Output noise voltage	V _{NO (2)}	2	R _g = 10kΩ BW = 20Hz~20kHz	_	0.7	1.5	mV _{rms}
	Ripple rejection ratio	R. R. (2)	2	f _{ripple} = 100Hz V _{ripple} = 0.775V _{rms} (0dBm)	-	-52	-40	dB
	Cross talk	C. T.	2	V _{OUT} = 0.775V _{rms} (0dBm)	—	-57	_	dB
	Input resistance	R _{IN}	2	f = 1kHz	—	33	_	kΩ

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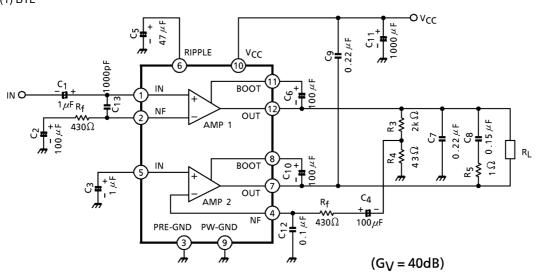
Typ. DC Voltage Of Each Terminal

 $(V_{CC} = 13.2V, Ta = 25^{\circ}C, dual mode test circuit)$

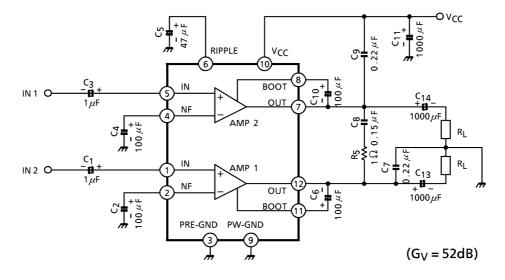
Term	inal No.	1	2	3	4	5	6	7	8	9	10	11	12
DC voltage	TA7280P	1.5	1.5	GND	1.5	1.5	6.4	6.4	12.3	GND	V _{CC}	12.3	6.4
(V)	TA7281P	6.4	12.3	V _{CC}	GND	12.3	6.4	6.4	1.5	1.5	GND	1.5	1.5

Test Circuit / Application Circuit

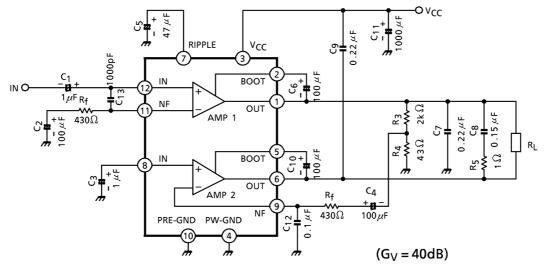
TA7280P (1) BTL



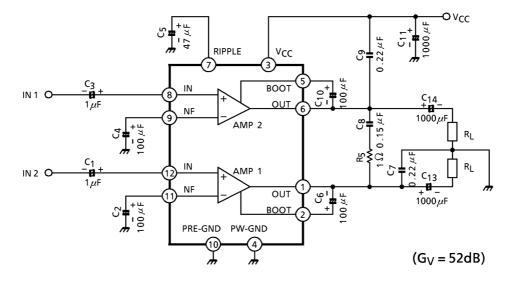
(2) DUAL

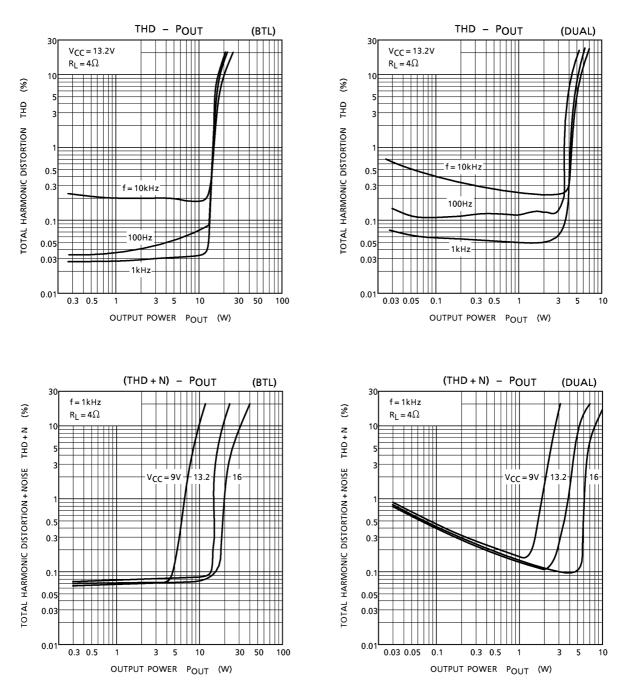


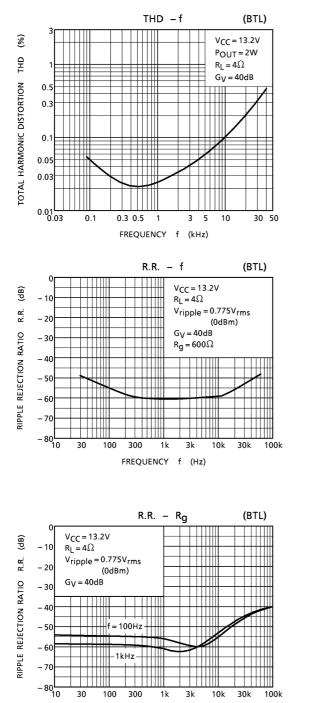
TA7281P (1) BTL



(2) DUAL







30

100 300 3k

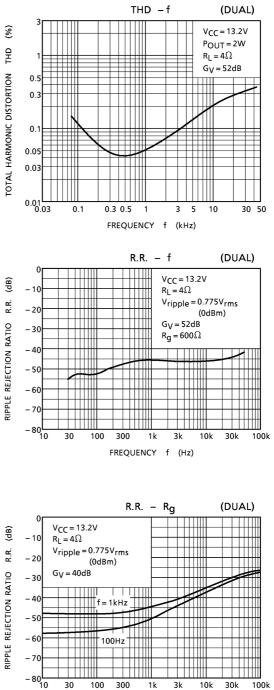
1k

SIGNAL SOURCE RESISTANCE Rg

10k 30k

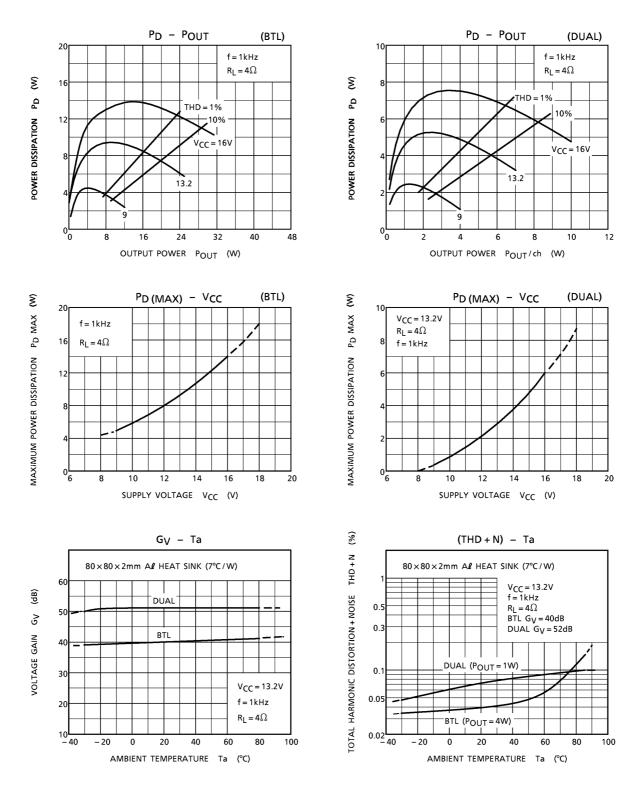
(Ω)

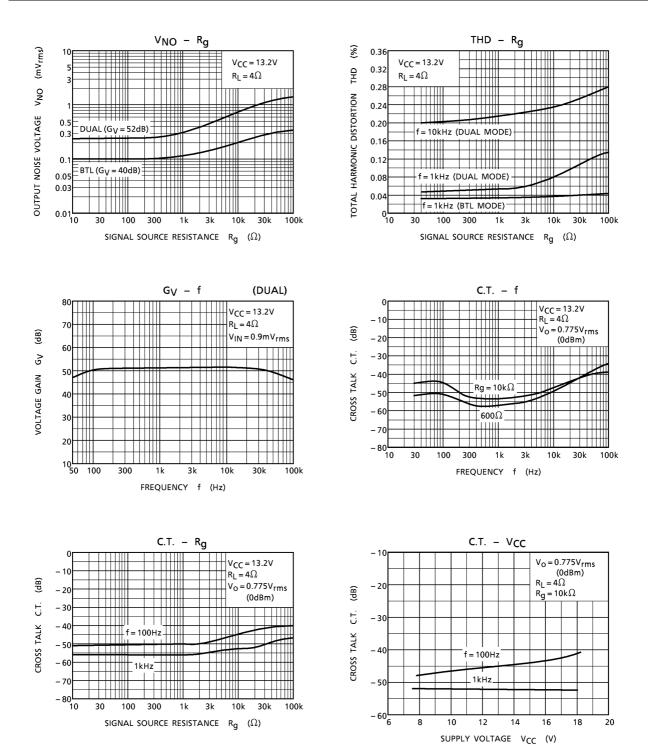
100k

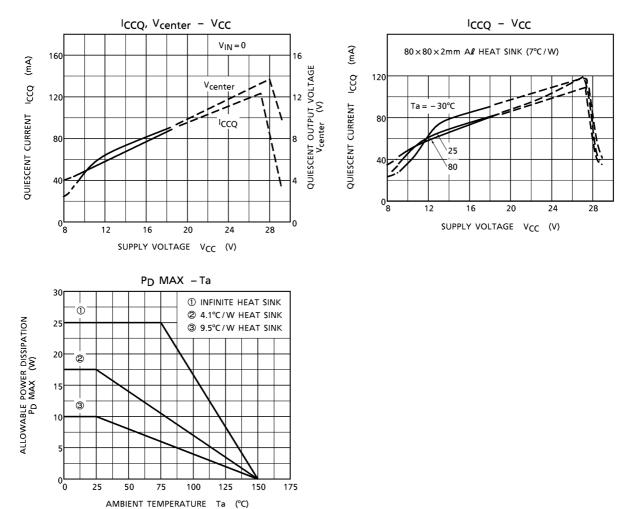


SIGNAL SOURCE RESISTANCE Rg

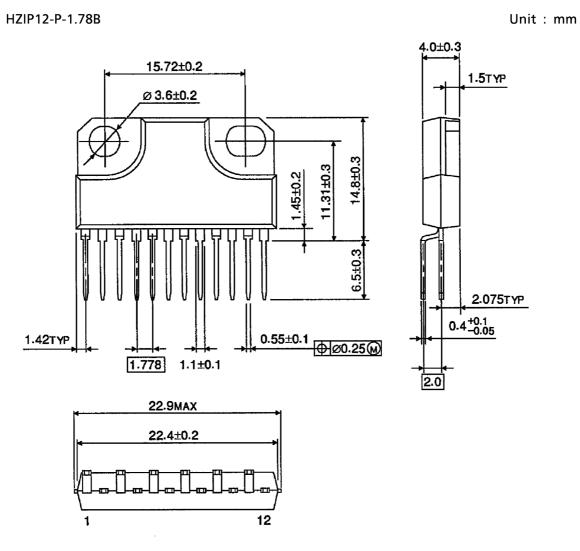
(Ω)







Package Dimensions



Weight: 4.04g (typ.)

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